MJD148

NPN Silicon Power Transistor

DPAK For Surface Mount Applications

Designed for general purpose amplifier and low speed switching applications.

Features

- High Gain -50 Min @ $I_C = 2.0$ A
- Low Saturation Voltage -0.5 V @ $I_C = 2.0 \text{ A}$
- High Current Gain Bandwidth Product f_T = 3.0 MHz Min @ I_C = 250 mAdc
- Epoxy Meets UL 94 V-0 @ 0.125 in
- ESD Ratings: Human Body Model, 3B; >8000 V Machine Model, C; >400 V
- Pb-Free Package is Available

MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|---|-----------------------------------|---------------|-----------|
| Collector–Emitter Voltage | V _{CEO} | 45 | Vdc |
| Collector-Base Voltage | V _{CB} | 45 | Vdc |
| Emitter-Base Voltage | V _{EB} | 5.0 | Vdc |
| Collector Current – Continuous – Peak | I _C | 4.0 7.0 | Adc |
| Base Current | Ι _Β | 50 | mAdc |
| Total Power Dissipation @ T _C = 25°C Derate above 25°C | P _D | 20 0.16 | W/°C |
| Total Power Dissipation (Note 1) @ T _A = 25°C Derate above 25°C | P _D | 1.75 0.014 | W W/°C |
| Operating and Storage Junction Temperature Range | T _J , T _{stg} | -55 to +150 | °C |

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
|--|-----------------|------|------|
| Thermal Resistance, Junction-to-Case | $R_{\theta JC}$ | 6.25 | °C/W |
| Thermal Resistance, Junction–to–Ambient (Note 1) | $R_{\theta JA}$ | 71.4 | °C/W |

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

 These ratings are applicable when surface mounted on the minimum pad sizes recommended.



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POWER TRANSISTOR 4.0 AMPERES 45 VOLTS, 20 WATTS



DPAK CASE 369C STYLE 1

MARKING DIAGRAM



Y = Year WW = Work Week J148 = Device Code G = Pb-Free Package

ORDERING INFORMATION

| Device | Package | Shipping [†] |
|-----------|-------------------|-----------------------|
| MJD148T4 | DPAK | 2500/Tape & Reel |
| MJD148T4G | DPAK (Pb-Free) | 2500/Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MJD148

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

| Characteristic | Test Conditions | Symbol | Min | Max | Unit |
|---|--|-----------------------|----------------------|--------------------|------|
| OFF CHARACTERISTICS | | | | | |
| Collector–Emitter Sustaining Voltage (Note 2) | $I_C = 100 \text{ mAdc}, I_B = 0$ | V _{CEO(sus)} | 45 | - | Vdc |
| Collector Cutoff Current | V _{CB} = 45 Vdc, I _E = 0 | I _{CBO} | - | 20 | μAdc |
| Emitter Cutoff Current | V _{BE} = 5 Vdc, I _C = 0 | I _{EBO} | - | 1 | mAdc |
| ON CHARACTERISTICS | | | | | |
| DC Current Gain (Note 2) | $\begin{split} I_C &= 10 \text{ mAdc, } V_{CE} = 5 \text{ Vdc} \\ I_C &= 0.5 \text{ Adc, } V_{CE} = 1 \text{ Vdc} \\ I_C &= 2 \text{ Adc, } V_{CE} = 1 \text{ Vdc} \\ I_C &= 3 \text{ Adc, } V_{CE} = 1 \text{ Vdc} \end{split}$ | h _{FE} | 40 85 50 30 | - 375 - - | 1 |
| Collector–Emitter Saturation Voltage (Note 2) | I _C = 2 Adc, I _B = 0.2 Adc | V _{CE(sat)} | - | 0.5 | Vdc |
| Base–Emitter On Voltage (Note 2) | I _C = 2 Adc, V _{CE} = 1 Vdc | V _{BE(on)} | - | 1.1 | Vdc |
| DYNAMIC CHARACTERISTICS | | | | | |
| Current-Gain-Bandwidth Product | $I_C = 250$ mAdc, $V_{CE} = 1$ Vdc, $f = 1$ MHz | f _T | 3 | _ | MHz |

^{2.} Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%.

TYPICAL CHARACTERISTICS

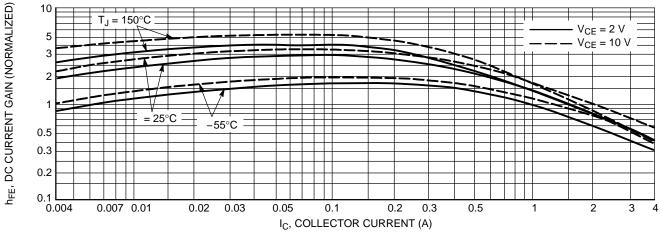


Figure 1. DC Current Gain

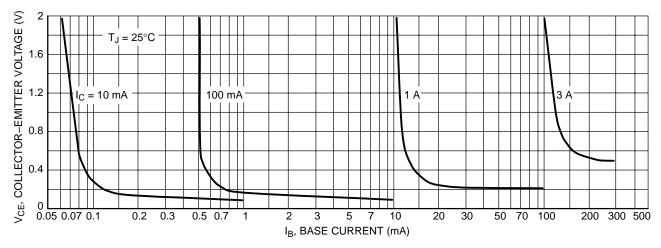


Figure 2. Collector Saturation Region

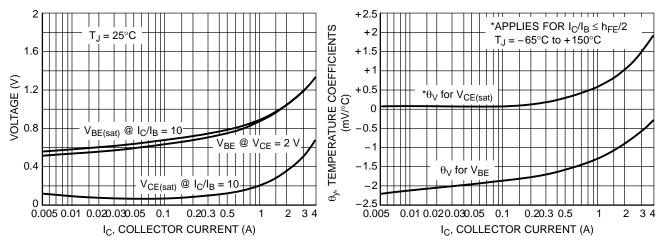


Figure 3. "On" Voltages

Figure 4. Temperature Coefficients

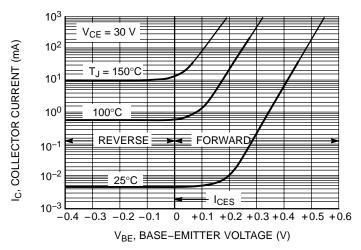


Figure 5. Collector Cut-Off Region

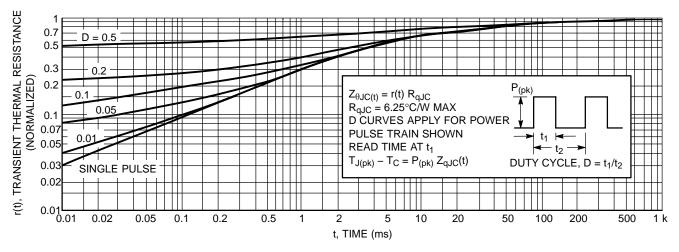


Figure 6. Thermal Response

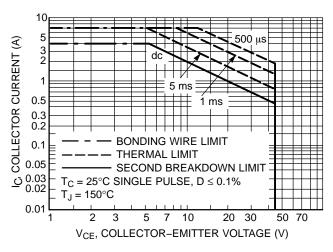


Figure 7. Maximum Rated Forward Bias

FORWARD BIAS SAFE OPERATING AREA INFORMATION

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate I_C-V_{CE} limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

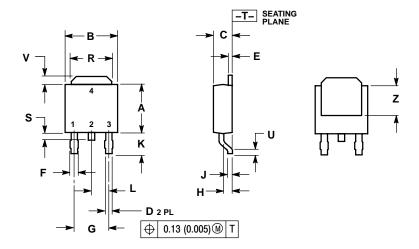
The data of Figure 7 is based on $T_{J(pk)} = 150^{\circ}\text{C}$; T_{C} is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} \leq 150^{\circ}\text{C}$. $T_{J(pk)}$ may be calculated from the data in Figure 6. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

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PACKAGE DIMENSIONS

DPAK (SINGLE GAUGE)

CASE 369C **ISSUE O**



- 1. DIMENSIONING AND TOLERANCING
- PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.

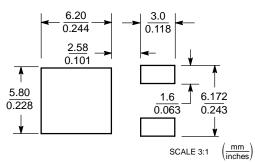
| | INC | HES | MILLIMETERS | | |
|-----|-----------|-------|-------------|------|--|
| DIM | MIN | MAX | MIN | MAX | |
| Α | 0.235 | 0.245 | 5.97 | 6.22 | |
| В | 0.250 | 0.265 | 6.35 | 6.73 | |
| С | 0.086 | 0.094 | 2.19 | 2.38 | |
| D | 0.027 | 0.035 | 0.69 | 0.88 | |
| E | 0.018 | 0.023 | 0.46 | 0.58 | |
| F | 0.037 | 0.045 | 0.94 | 1.14 | |
| G | 0.180 | BSC | 4.58 BSC | | |
| Н | 0.034 | 0.040 | 0.87 | 1.01 | |
| J | 0.018 | 0.023 | 0.46 | 0.58 | |
| K | 0.102 | 0.114 | 2.60 | 2.89 | |
| L | 0.090 BSC | | 2.29 | BSC | |
| R | 0.180 | 0.215 | 4.57 | 5.45 | |
| S | 0.025 | 0.040 | 0.63 | 1.01 | |
| U | 0.020 | | 0.51 | | |
| ٧ | 0.035 | 0.050 | 0.89 | 1.27 | |
| 7 | 0.155 | | 3 93 | | |

STYLE 1:

- PIN 1. BASE 2. COLLECTOR

 - EMITTER COLLECTOR

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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